

IN THE CLAIMS:

Please amend the claims as follows:

1. (Currently Amended) A semiconductor device assembly of a plurality of semiconductor device assemblies, comprising:
a semiconductor die having an active surface having a plurality of bond pads thereon and an opposing second surface;
at least one projection connected to at least one bond pad of ~~said~~the plurality of bond pads on the active surface of ~~said~~the semiconductor die for ~~direct connection~~ flip-chip bonding to a substrate, ~~said~~the at least one projection including one of at least one solder ball and at least one solder bump; and
a paddle frame of a plurality of paddle frames ~~having no electrical leads for connection to a semiconductor die, the paddle frame~~ including a pair of side rails, a plurality of cross-members, and a plurality of generally centrally positioned paddles, ~~paddle of a plurality of paddle frames~~ having the pair of side rails and the plurality of cross members connected to ~~said paddle~~ a generally centrally positioned paddle of the paddle frame by a plurality of paddle support bars, ~~said~~the second surface of ~~said~~the semiconductor die being secured to ~~said~~the paddle, the paddle being attached to the side rail by at least two of the plurality of paddle support bars and being attached to the cross members by at least two of the plurality of support bars.
2. (Currently Amended) The semiconductor device assembly of claim 1, wherein ~~said~~the at least one projection includes a plurality of projections comprising a ball grid array (BGA) of solder balls.
3. (Currently Amended) The semiconductor device assembly of claim 1, wherein ~~said~~the at least one projection comprises at least one ball deposited by a wire bonding machine.

4. (Currently Amended) The semiconductor device assembly of claim 1, wherein ~~said~~the at least one projection comprises at least one stud bump deposited by a wire bonding machine.

5. (Currently Amended) The semiconductor device assembly of claim 1, further comprising:
an electrically non-conductive adhesive layer securing ~~said~~the second surface to ~~said~~the generally centrally positioned paddle.

6. (Currently Amended) The semiconductor device assembly of claim 5, wherein ~~said~~the adhesive layer comprises one of epoxy and polyimide.

7. (Withdrawn) The semiconductor device assembly of claim 1, further comprising:
an electrically conductive adhesive layer securing said second surface of said semiconductor die to said generally centrally positioned paddle.

8. (Withdrawn) The semiconductor device assembly of claim 7, wherein said electrically conductive adhesive layer comprises a eutectic material.

9. (Withdrawn) The semiconductor device assembly of claim 7, wherein said electrically conductive adhesive layer comprises a gold-silicon eutectic material.

10. (Withdrawn) The semiconductor device assembly of claim 7, wherein said electrically conductive adhesive layer comprises a metal-filled polymer, said metal filling comprising a heat conductive material.

11. (Withdrawn) The semiconductor device assembly of claim 7, wherein said electrically conductive adhesive layer comprises conductive polyimide.

12. (Canceled)

13. (Canceled)

14. (Currently Amended) A semiconductor device assembly of a plurality of semiconductor device assemblies, comprising:
a semiconductor die having an active surface having at least one bond pad thereon and an opposing second surface;
at least one projection secured to ~~said~~the at least one bond pad on ~~said~~the active surface of said semiconductor die configured for flip-chip connection~~-connected~~ to a substrate, ~~said~~the at least one projection including one of at least one solder ball and at least one solder bump;
and
a metal paddle from a paddle frame having no electrical leads for connection to the semiconductor die of a plurality of paddle frames connected by a pair of rails having a plurality of cross members therebetween, said second surface of ~~said~~the semiconductor die being attached to ~~said~~the paddle, ~~said~~the metal paddle attached to at least one side rail by at least a plurality of paddle support bars and being attached to a plurality of cross members by ~~said~~the support bars.

15. (Currently Amended) The semiconductor device assembly of claim 14, wherein ~~said~~the at least one projection comprises a ball grid array (BGA) of solder balls.

16. (Currently Amended) The semiconductor device assembly of claim 14, wherein ~~said~~the at least one projection comprises at least one ball deposited by a wire bonding machine.

17. (Currently Amended) The semiconductor device assembly of claim 14, wherein ~~said~~the at least one projection comprises at least one stud bump deposited by a wire bonding machine.

18. (Currently Amended) The semiconductor device assembly of claim 14, further comprising:
an electrically non-conductive adhesive layer attaching ~~said~~the second surface to ~~said~~the paddle.

19. (Currently Amended) The semiconductor device assembly of claim 18, wherein ~~said~~the adhesive layer comprises one of epoxy and polyimide.

20. (Withdrawn) The semiconductor device assembly of claim 14, further comprising:
an electrically conductive adhesive layer attaching said second surface to said metal paddle.

21. (Withdrawn) The semiconductor device assembly of claim 20, wherein said electrically conductive adhesive layer comprises a eutectic material.

22. (Withdrawn) The semiconductor device of claim 20, wherein said electrically conductive adhesive layer comprises a gold-silicon eutectic material.

23. (Withdrawn) The semiconductor device assembly of claim 21, wherein said electrically conductive adhesive layer comprises a metal-filled polymer, said metal filling comprising a heat conductor.

24. (Withdrawn) The semiconductor device assembly of claim 21, wherein said electrically conductive layer comprises conductive polyimide.

25. (Currently Amended) The semiconductor device assembly of claim 14, further comprising:
a substrate having a plurality of circuit connections, ~~said~~the at least one bond pad connected to at least one circuit connection of ~~said~~the plurality of circuit connections.

26. (Currently Amended) The semiconductor device assembly of claim 25, further comprising:
sealant packaging covering a portion of ~~said~~the semiconductor die and a portion of ~~said~~the substrate.

27. (Currently Amended) A semiconductor device assembly of a plurality of semiconductor device assemblies, comprising:
a semiconductor die having an active surface having a plurality of bond pads thereon and an opposing second surface;
a plurality of projections connected to ~~said~~the plurality of bond pads for direct connection to a host circuit board, ~~said~~the plurality of projections including one of a plurality of solder balls and a plurality of solder bumps; and
a metallic paddle having no electrical leads for connection to a semiconductor die secured to ~~said~~the second surface of ~~said~~the semiconductor die, ~~said~~the metallic paddle being attached to at least one side rail by at least a plurality of paddle support bars and being attached to a plurality of cross members by ~~said~~the support bars of a paddle frame.

28. (Currently Amended) The semiconductor device assembly of claim 27, wherein ~~said~~the plurality of projections comprises a ball grid array (BGA) of solder balls.

29. (Currently Amended) The semiconductor device assembly of claim 27, wherein ~~said~~the plurality of projections comprises balls deposited by a wire bonding machine.

30. (Currently Amended) The semiconductor device assembly of claim 27, wherein ~~said~~the plurality of projections comprises a plurality of stud bumps deposited by a wire bonding machine.

31. (Currently Amended) The semiconductor device assembly of claim 27, further comprising:

an electrically non-conductive adhesive layer connecting ~~said~~the second surface to ~~said~~the metallic paddle.

32. (Currently Amended) The semiconductor device assembly of claim 31, wherein ~~said~~the adhesive layer comprises one of epoxy and polyimide.

33. (Withdrawn) The semiconductor device assembly of claim 27, further comprising: an electrically conductive adhesive layer connecting said second surface to said metallic paddle.

34. (Withdrawn) The semiconductor device assembly of claim 33, wherein said electrically conductive adhesive layer comprises a eutectic material.

35. (Withdrawn) The semiconductor device assembly of claim 33, wherein said electrically conductive adhesive layer comprises a gold-silicon eutectic material.

36. (Withdrawn) The semiconductor device assembly of claim 33, wherein said electrically conductive adhesive layer comprises a metal-filled polymer, said metal filling comprising a heat conductive material.

37. (Withdrawn) The semiconductor device assembly of claim 33, wherein said electrically conductive adhesive layer comprises conductive polyimide.

38. (Currently Amended) The semiconductor device of claim 27, further comprising: a substrate having a plurality of circuit connections, ~~said~~the plurality of bond pads connected to ~~said~~the plurality of circuit connections.

39. (Currently Amended) The semiconductor device assembly of claim 38, further comprising:
sealant packaging covering a portion of ~~said~~the semiconductor die and a portion of ~~said~~the substrate.